74F32 Quad 2-Input OR Gate

74F32 Quad 2-Input OR Gate

General Description

FAIRCHILD

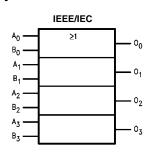
SEMICONDUCTOR

This device contains four independent gates, each of which performs the logic OR function.

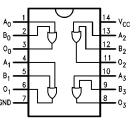
Ordering Code:

Order Number	Package Number	Package Description				
74F32SC	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150 Narrow				
74F32SJ	M14D	14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide				
74F32MTC	MTC14	14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide				
74F32PC	N14A	14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide				
Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.						

Logic Symbol



Connection Diagram



Unit Loading/Fan Out

Pin Names	Description	U.L. HIGH/LOW	Input I _{IH} /I _{IL} Output I _{OH} /I _{OL}	
A _n , B _n	Inputs	1.0/1.0	20 µA/–0.6 mA	
O _n	Outputs	50/33.3	–1 mA/20 mA	

© 2000 Fairchild Semiconductor Corporation DS009463

www.fairchildsemi.com

74F32

Absolute Maximum Ratings(Note 1)

Storage Temperature	-65°C to +150°C				
Ambient Temperature under Bias	$-55^{\circ}C$ to $+125^{\circ}C$				
Junction Temperature under Bias	$-55^{\circ}C$ to $+150^{\circ}C$				
$V_{\mbox{\scriptsize CC}}$ Pin Potential to Ground Pin	-0.5V to +7.0V				
Input Voltage (Note 2)	-0.5V to +7.0V				
Input Current (Note 2)	-30 mA to +5.0 mA				
Voltage Applied to Output					
in HIGH State (with $V_{CC} = 0V$)					
Standard Output	–0.5V to V _{CC}				
3-STATE Output	-0.5V to +5.5V				
Current Applied to Output					
in LOW State (Max)	twice the rated I_{OL} (mA)				
ESD Last Passing Voltage (Min)	4000V				

Recommended Operating Conditions

Free Air Ambient	Temperature
Supply Voltage	

0°C to +70°C +4.5V to +5.5V

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

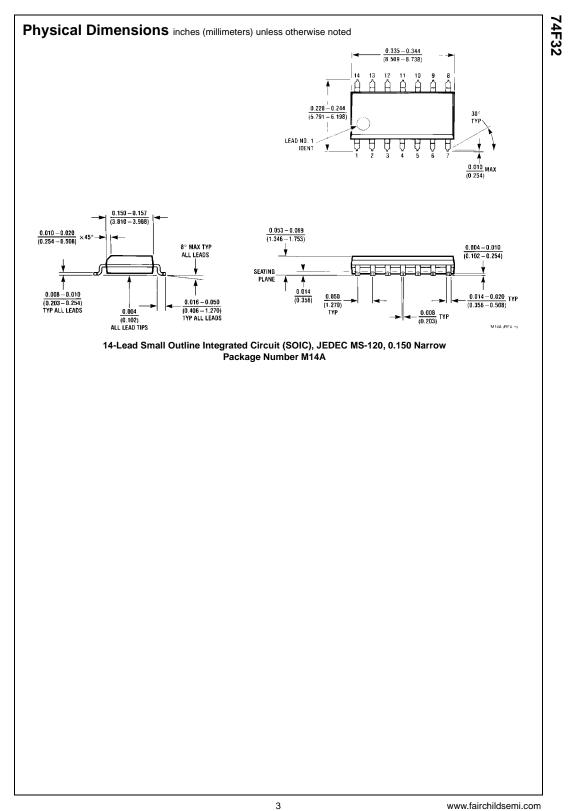
DC Electrical Characteristics

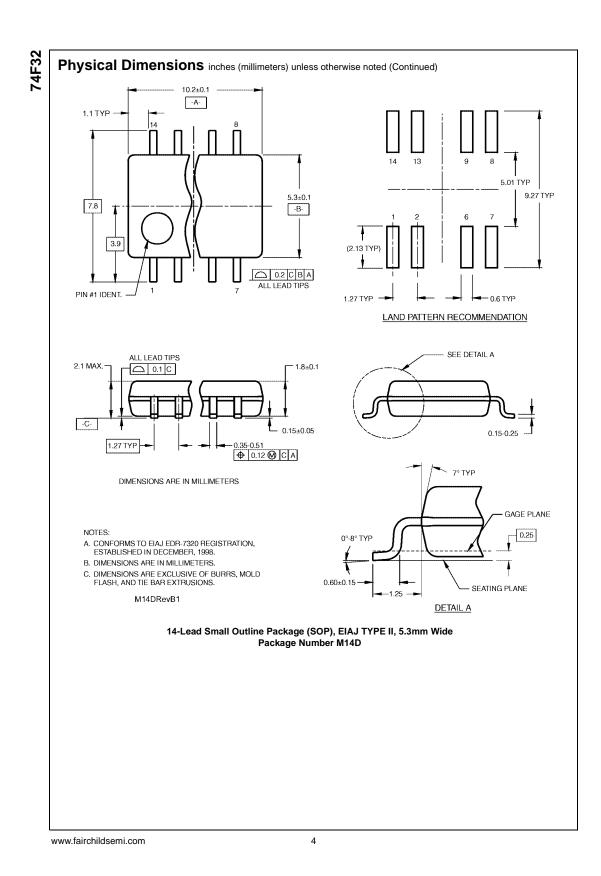
Symbol	Parameter		Min	Тур	Max	Units	V _{cc}	Conditions	
VIH	Input HIGH Voltage		2.0			V		Recognized as a HIGH Signal	
VIL	Input LOW Voltage				0.8	V		Recognized as a LOW Signal	
V _{CD}	Input Clamp Diode Voltage				-1.2	V	Min	I _{IN} = -18 mA	
V _{OH}	Output HIGH	10% V _{CC}	2.5			V	Min	I _{OH} = -1 mA	
	Voltage	5% V _{CC}	2.7					$I_{OH} = -1 \text{ mA}$	
V _{OL}	Output LOW	10% V _{CC}			0.5	V	Min	I _{OL} = 20 mA	
	Voltage				0.5	v	IVIIII		
IIH	Input HIGH				5.0	μA	Max	V _{IN} = 2.7V	
	Current				5.0	μΛ			
I _{BVI}	Input HIGH Current				7.0	μA	Max	V _{IN} = 7.0V	
	Breakdown Test				7.0	μΛ	IVIAA	v _{IN} = 7.0v	
ICEX	Output HIGH				50	μA	Max	$V_{OUT} = V_{CC}$	
	Leakage Current				50	μΛ	IVIAN	•001 - •CC	
V _{ID}	Input Leakage		4.75			V	0.0	I _{ID} = 1.9 μA	
	Test		4.75			v	0.0	All Other Pins Grounded	
I _{OD}	Output Leakage				3.75	μA	0.0	V _{IOD} = 150 mV	
	Circuit Current				5.75	μΛ	0.0	All Other Pins Grounded	
IIL	Input LOW Current				-0.6	mA	Max	V _{IN} = 0.5V	
I _{OS}	Output Short-Circuit Current		-60		-150	mA	Max	$V_{OUT} = 0V$	
I _{CCH}	Power Supply Current			6.1	9.2	mA	Max	V _O = HIGH	
I _{CCL}	Power Supply Current			10.3	15.5	mA	Max	$V_{O} = LOW$	

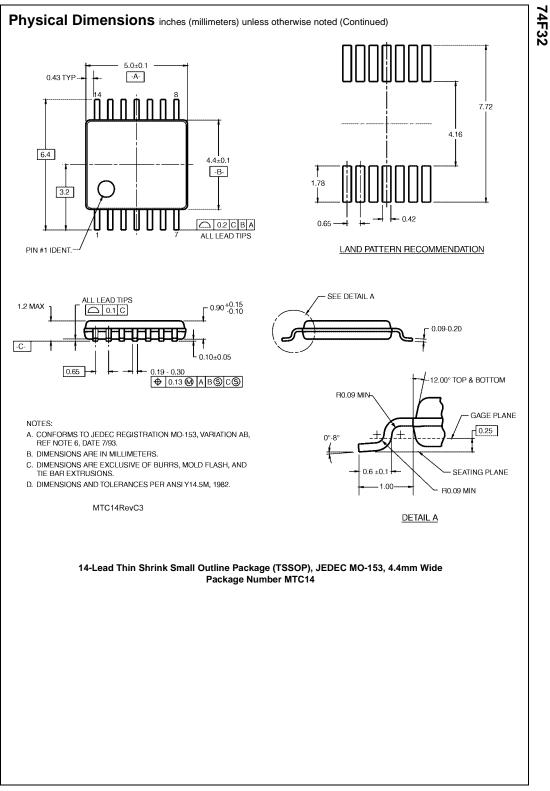
AC Electrical Characteristics

Symbol	Parameter	$T_{A} = +25^{\circ}C$ $V_{CC} = +5.0V$ $C_{L} = 50 \text{ pF}$			T _A = -55°C V _{CC} = C _L = 1		$T_{A} = 0^{\circ}C \text{ to } +70^{\circ}C$ $V_{CC} = +5.0V$ $C_{L} = 50 \text{ pF}$		Units
		Min	Тур	Max	Min	Max	Min	Max	
t _{PLH}	Propagation Delay	3.0	4.2	5.6	3.0	7.5	3.0	6.6	ns
t _{PHL}	A _n , B _n to O _n	3.0	4.0	5.3	2.5	7.5	3.0	6.3	115

www.fairchildsemi.com

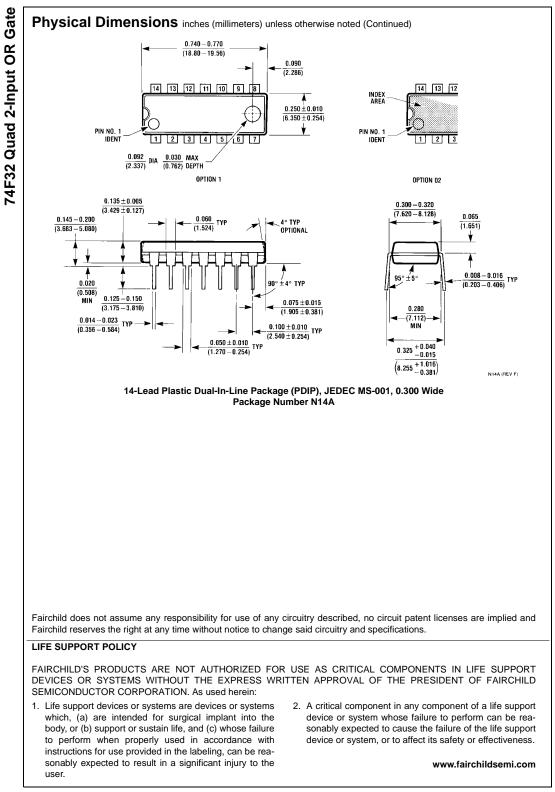






www.fairchildsemi.com

5



www.fairchildsemi.com

6